# Vishay Semiconductors Optocoupler, Phototransistor Output, with Base Connection in SOIC-8 Package



| PARAMETER                                    | TEST CONDITION | SYMBOL               | VALUE         | UNIT      |
|--|----------------|----------------------|---------------|-----------|
| INPUT  |                |                      |               |           |
| Peak reverse voltage                         |                | V <sub>R</sub>       | 6             | V         |
| Forward continuous current                   |                | l <sub>F</sub>       | 60            | mA        |
| Power dissipation                            |                | P <sub>diss</sub>    | 90            | mW        |
| Derate linearly from 25 °C                   |                |                      | 1.2           | mW/°C     |
| OUTPUT                                       |                |                      |               |           |
| Collector emitter breakdown voltage          |                | BV <sub>CEO</sub>    | 70            | V         |
| Emitter collector breakdown voltage          |                | BV <sub>ECO</sub>    | 7             | V         |
| Collector-base breakdown voltage             |                | BV <sub>CBO</sub>    | 70            | V         |
| I <sub>CMAX DC</sub>                         |                | I <sub>CMAX DC</sub> | 50            | mA        |
| I <sub>CMAX</sub>                            | t < 1 ms       | I <sub>CMAX</sub>    | 100           | mA        |
| Power dissipation                            |                | P <sub>diss</sub>    | 150           | mW        |
| Derate linearly from 25 °C                   |                |                      | 2             | mW/°C     |
| COUPLER                                      |                |                      |               |           |
| Isolation test voltage                       |                | $V_{ISO}$            | 4000          | $V_{RMS}$ |
| Total package dissipation (LED and detector) |                | P <sub>tot</sub>     | 240           | mW        |
| Derate linearly from 25 °C                   |                |                      | 3.3           | mW/°C     |
| Operating temperature                        |                | T <sub>amb</sub>     | - 55 to + 100 | °C        |
| Storage temperature                          |                | T <sub>stg</sub>     | - 55 to + 150 | °C        |
| Soldering time                               | at 260 °C      |                      | 10            | s         |

#### Note

 $T_{amb}$  = 25 °C, unless otherwise specified.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

| ELECTRICAL CHARACTERISTCS             |   |      |                    |      |      |      |      |
|---------------------------------------|---|------|--------------------|------|------|------|------|
| PARAMETER                             | TEST CONDITION                            | PART | SYMBOL             | MIN. | TYP. | MAX. | UNIT |
| INPUT                                 |   |      |                    |      |      |      |      |
| Forward voltage                       | $I_F = 10 \text{ mA}$                     |      | $V_{F}$            |      | 1.3  | 1.5  | ٧    |
| Reverse current                       | V <sub>R</sub> = 6 V                      |      | I <sub>R</sub>     |      | 0.1  | 100  | μΑ   |
| Capacitance                           | $V_R = 0 V$                               |      | Co                 |      | 13   |      | pF   |
| OUTPUT                                |   |      |                    |      |      |      |      |
| Collector emitter breakdown voltage   | $I_C = 100  \mu A$                        |      | BV <sub>CEO</sub>  | 70   |      |      | V    |
| Emitter collector breakdown voltage   | $I_E = 100 \mu A$                         |      | BV <sub>ECO</sub>  | 7    | 10   |      | V    |
| Collector emitter leakage current     | V <sub>CE</sub> = 10 V                    |      | I <sub>CEO</sub>   |      | 5    | 50   | nA   |
| COUPLER                               |   |      |                    |      |      |      |      |
| Saturation voltage, collector emitter | $I_C = 2 \text{ mA}, I_F = 10 \text{ mA}$ |      | V <sub>CEsat</sub> |      |      | 0.4  | V    |
| Capacitance, input to output          |   |      | C <sub>IO</sub>    |      | 0.5  |      | pF   |
| Resistance, input to output           |   |      | R <sub>IO</sub>    |      | 100  |      | GΩ   |

#### Note

 $T_{amb}$  = 25 °C, unless otherwise specified.

Minimum and maximum values were tested requierements. Typical values are characteristics of the device and are the result of engineering evaluations. Typical values are for information only and are not part of the testing requirements.



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| CURRENT TRANSFER RATIO |   |         |        |      |      |      |                       |
|------------------------|---|---------|--------|------|------|------|-----------------------|
| PARAMETER              | TEST CONDITION                                | PART    | SYMBOL | MIN. | TYP. | MAX. | UNIT                  |
| Current transfer ratio |   | IL205AT | CTR    | 40   |      | 80   | %<br>%<br>%<br>%<br>% |
|                        | I <sub>F</sub> = 10 mA, V <sub>CE</sub> = 5 V | IL206AT | CTR    | 63   |      | 125  | %                     |
|                        |   | IL207AT | CTR    | 100  |      | 200  | %                     |
|                        |   | IL208AT | CTR    | 100  |      | 320  | %                     |
|                        |   | IL205AT | CTR    | 13   | 25   |      | %                     |
|                        | $I_F = 1 \text{ mA}, V_{CE} = 5 \text{ V}$    | IL206AT | CTR    | 22   | 40   |      | %                     |
|                        |   | IL207AT | CTR    | 34   | 60   |      | %                     |
|                        |   | IL208AT | CTR    | 56   | 95   |      | %                     |

| SWITCHING CHARACTERISTICS |  |      |                                    |      |      |      |      |
|---------------------------|--|------|------------------------------------|------|------|------|------|
| PARAMETER                 | TEST CONDITION   | PART | SYMBOL                             | MIN. | TYP. | MAX. | UNIT |
| Switching time            | $I_C = 2 \text{ mA}, \ R_L = 100 \ \Omega, \\ V_{CC} = 10 \ V$ |      | t <sub>on</sub> , t <sub>off</sub> |      | 3    |      | μs   |

| PARAMETER  | TEST CONDITION         | SYMBOL | MIN. | TYP.      | MAX. | UNIT |
|--|------------------------|--------|------|-----------|------|------|
| Climatic classification (according to IEC 68 part 1) |                        |        |      | 55/100/21 |      |      |
| Comparative tracking index                           |                        | CTI    | 175  |           | 399  |      |
| V <sub>IOTM</sub>                                    |                        |        | 6000 |           |      | V    |
| V <sub>IORM</sub>                                    |                        |        | 560  |           |      | V    |
| P <sub>SO</sub>                                      |                        |        |      |           | 350  | mW   |
| I <sub>SI</sub>                                      |                        |        |      |           | 150  | mA   |
| T <sub>SI</sub>                                      |                        |        |      |           | 165  | °C   |
| Creepage   |                        |        | 4    |           |      | mm   |
| Clearance  |                        |        | 4    |           |      | mm   |
| Insulation thickness, reinforced rated               | per IEC 60950 2.10.5.1 |        | 0.2  |           |      | mm   |

#### Note

As per IEC 60747-5-2, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

Document Number: 83614 Rev. 1.9, 08-May-08

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#### **TYPICAL CHARACTERISTICS**

T<sub>amb</sub> = 25 °C, unless otherwise specified

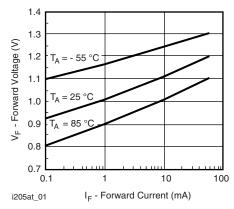


Fig. 1 - Forward Voltage vs. Forward Current

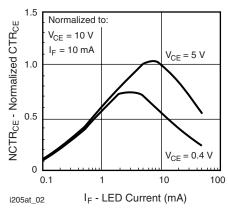


Fig. 2 - Normalized Non-Saturated and Saturated CTR<sub>CE</sub> vs. LED Current

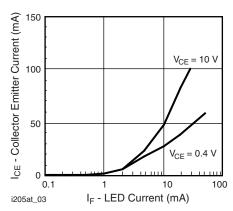


Fig. 3 - Collector Emitter Current vs. LED Current

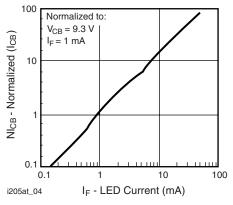


Fig. 4 - Normalized Collector-Base Photocurrent vs. LED Current

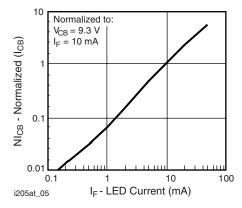


Fig. 5 - Normalized Collector-Base Photocurrent vs. LED Current

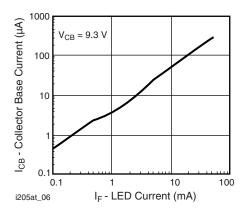


Fig. 6 - Collector Emitter Photocurrent vs. LED Current



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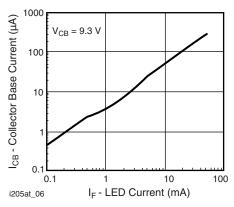


Fig. 7 - Collector Emitter Photocurrent vs. LED Current

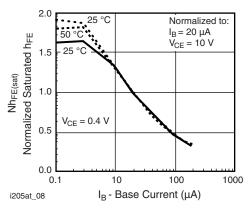


Fig. 9 - Typical Switching Characteristics vs. Base Resistance (Saturated Operation)

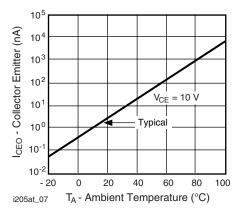
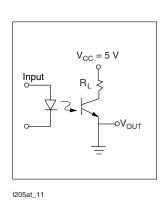


Fig. 8 - Base Current vs.  $I_F$  and  $h_{FE}$ 



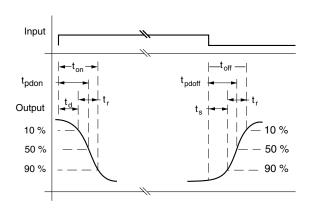
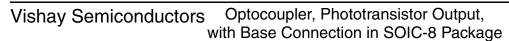
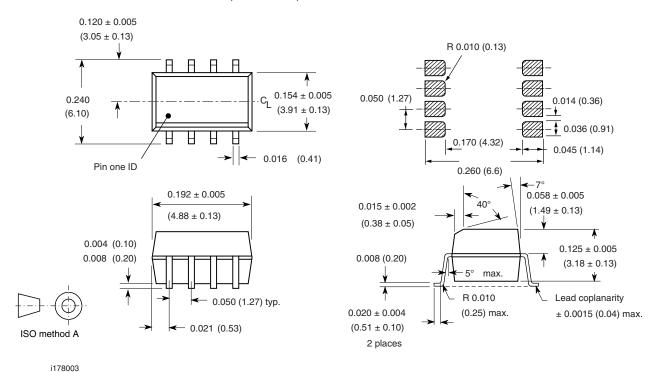


Fig. 10 Switching Test Circuit





#### **PACKAGE DIMENSIONS** in inches (millimeters)





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#### **OZONE DEPLETING SUBSTANCES POLICY STATEMENT**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively.
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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Document Number: 83614 Rev. 1.9, 08-May-08



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Document Number: 91000 www.vishay.com Revision: 18-Jul-08